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Vishay Semiconductors

RoHS

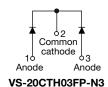
COMPLIANT

HALOGEN FREE

# Hyperfast Rectifier, 2 x 10 A FRED Pt®



3L TO-220 FullPAK



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 10 A			
V <sub>R</sub>	300 V			
V <sub>F</sub> at I <sub>F</sub>	0.85 V			
t <sub>rr</sub> typ.	See Recovery table			
T <sub>J</sub> max.	175 °C			
Package	3L TO-220 FullPAK			
Circuit configuration	Common cathode			

#### **FEATURES**

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL pending
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		$V_{RRM}$		300	V
Average rectified forward current ——	per diode	I <sub>F(AV)</sub>	T <sub>C</sub> = 135 °C	10	
Average rectilled forward current	per device			20	Α
Non-repetitive peak surge current		I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	120	
Operating junction and storage temperat	ures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	300	-	-	.,
Forward voltage	I <sub>F</sub> = 10 A	-	1.05	1.25	V	
Forward voltage V <sub>F</sub>		I <sub>F</sub> = 10 A, T <sub>J</sub> = 125 °C	-	0.85	0.95	
Reverse leakage current I <sub>R</sub>		$V_R = V_R$ rated	-	-	20	
		$T_J = 125  ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	6	200	μΑ
Junction capacitance	C <sub>T</sub>	$V_R = 300 \text{ V}$ -		30	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8 -		nΗ		



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	-	35	
Reverse recovery time	t <sub>rr</sub>	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	-	30	
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 10 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	31	-	ns - A
		T <sub>J</sub> = 125 °C		-	42	-	
Peak recovery current I <sub>RRN</sub>	1	T <sub>J</sub> = 25 °C		-	2.4	-	
	IRRM	T <sub>J</sub> = 125 °C		-	5.6	-	
Reverse recovery charge	I Q <sub>rr</sub> ⊢	T <sub>J</sub> = 25 °C		-	36	-	nC
		T <sub>J</sub> = 125 °C		-	120	-	TIC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction-to-case per diode	R <sub>thJC</sub>	Mounting surface, flat, smooth, and greased	-	-	3.9	°C/W
Marking device		Case style 3L TO-220 FullPAK	20CTH03FP			

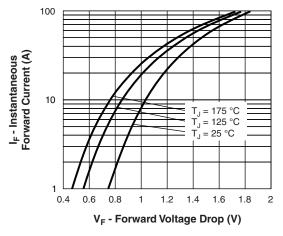


Fig. 1 - Typical Forward Voltage Drop Characteristics

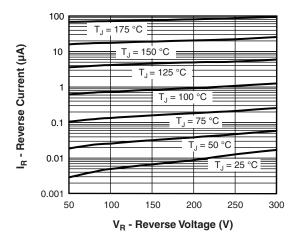


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



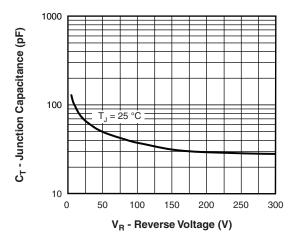


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

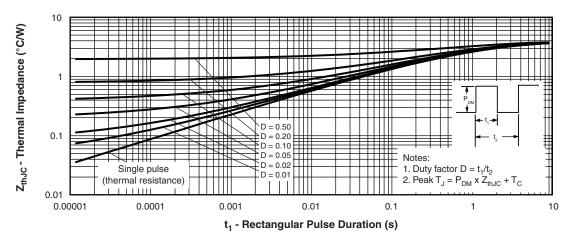


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

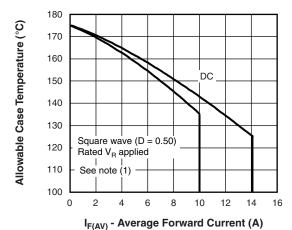


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

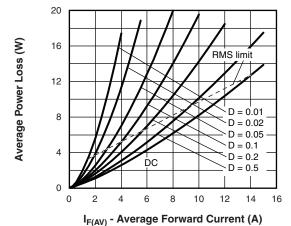
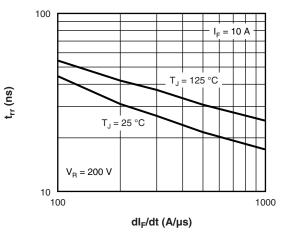


Fig. 6 - Forward Power Loss Characteristics

#### Note

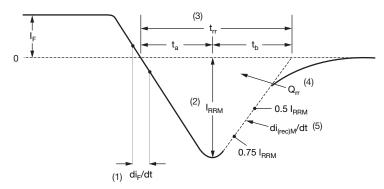
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times \text{R}_{\text{th,JC}}; \\ \text{Pd} = \text{forward power loss} = I_{\text{F(AV)}} \times \text{V}_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 5)}; \\ \text{Pd}_{\text{REV}} = \text{inverse power loss} = \text{V}_{\text{R1}} \times \text{I}_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } \text{V}_{\text{R1}} = \text{rated V}_{\text{R}} \\ \end{array}$ 



1000 T<sub>J</sub> = 125 °C T<sub>J</sub> = 25 °C V<sub>R</sub> = 200 V 100 dl<sub>E</sub>/dt (A/μs)

Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

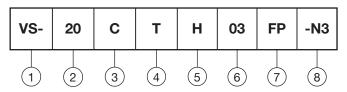
(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 9 - Reverse Recovery Waveform and Definitions



### **ORDERING INFORMATION TABLE**

### **Device code**



1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

**3** - C = common cathode

- T = TO-220, D<sup>2</sup>PAK (TO-263AB)

5 - H = hyperfast recovery

6 - Voltage rating (03 = 300 V)

7 - FP = 3L TO-220 FullPAK

8 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

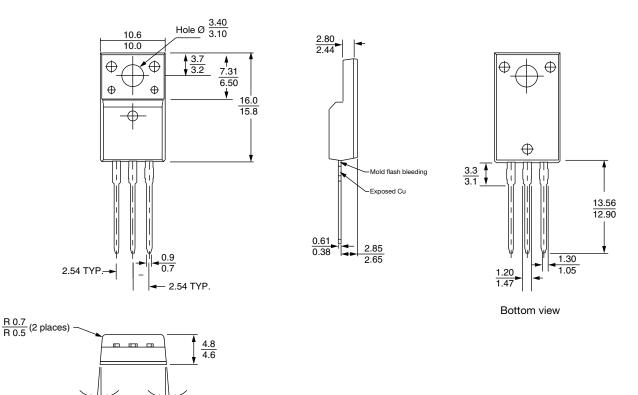
ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-20CTH03FP-N3	50	1000	Antistatic plastic tube	

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96155			
Part marking information	www.vishay.com/doc?95456			
SPICE model	www.vishay.com/doc?96584			



### **3L TO-220 FullPAK**

### **DIMENSIONS** in millimeters



### **Notes**

(1) All dimensions are in mm

 $5^{\circ} \pm 0.5^{\circ}$ 

(2) Package body size exclude mold flash and burrs. Moldflash should be less than 6 mils

 $5^{\circ} \pm 0.5^{\circ}$ 

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